Product data sheet

1. General description

PNP general-purpose double transistor in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package. NPN complement: BC847BS-Q.

2. Features and benefits

- · Low collector capacitance
- Low collector-emitter saturation voltage
- · Closely matched current gain
- Reduces number of components and boardspace
- No mutual interference between the transistors
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

· General purpose switching and amplification.

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor						
V _{CEO}	collector-emitter voltage	open base	-	-	-45	V
I _C	collector current		-	-	-100	mA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	200	-	450	



PNP general purpose double transistor

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	D. D. D.	C1 B2 E2
2	B1	base TR1	6 5 4	
3	C2	collector TR2		(TR1 TR2)
4	E2	emitter TR2		
5	B2	base TR2	∐1 ∐2 ∐3	
6	C1	collector TR1	TSSOP6 (SOT363)	sym138

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BC857BS-Q		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363		

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
BC857BS-Q	3F%

[1] % = placeholder for manufacturing site code

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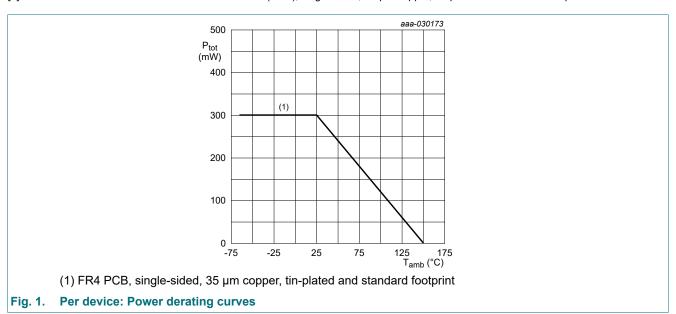
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	or					
V _{CBO}	collector-base voltage	open emitter		-	-50	V
V_{CEO}	collector-emitter voltage	open base		-	-45	V
V_{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-100	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-200	mA
I _{BM}	peak base current			-	-200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C
Per device	•					
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.



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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transiste	or						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	568	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	230	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.

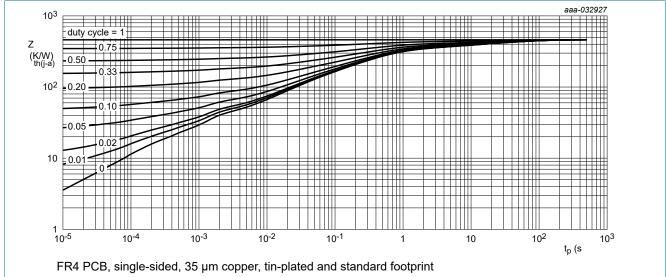


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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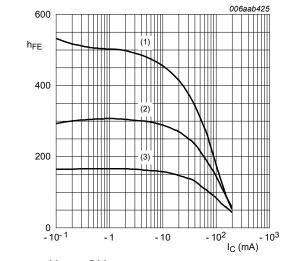
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	or					
$V_{(BR)CBO}$	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A; T _{amb} = 25 °C	50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	45	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0 \text{ A}; I_E = -100 \mu\text{A}; T_{amb} = 25 \text{ °C}$	5	-	-	V
I _{CBO}	collector-base cut-off	V _{CB} = -30 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-15	nA
	current	V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C	-	-	-5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -2 mA; T _{amb} = 25 °C	200	-	450	
V _{CEsat}	V _{CEsat} collector-emitter saturation voltage	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C	-	-	-100	mV
		I_C = -100 mA; I_B = -5 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.02; T_{amb} = 25 °C	-	-	-400	mV
V _{BEsat}	base-emitter saturation voltage	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C	-	-755	-	mV
V _{BE}	base-emitter voltage	V _{CE} = -5 V; I _C = 2 mA; T _{amb} = 25 °C	-600	-655	-750	mV
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	2.2	pF
C _e	emitter capacitance	$V_{EB} = -0.5 \text{ V; } I_{C} = 0 \text{ A; } i_{c} = 0 \text{ A;}$ $f = 1 \text{ MHz; } T_{amb} = 25 \text{ °C}$	-	10	-	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	100	-	-	MHz
NF	noise figure	V_{CE} = -5 V; I_{C} = -0.2 mA; R_{S} = 2 k Ω ; f = 1 kHz; B = 200 Hz; T_{amb} = 25 °C	-	2	-	dB

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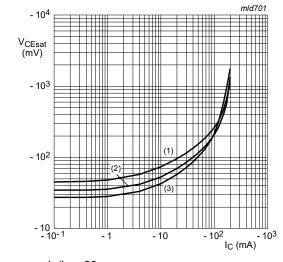
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$$V_{CE} = -5 \text{ V}$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$





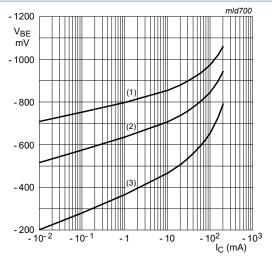
$$I_{\rm C}/I_{\rm B}=20$$

$$(1) T_{amb} = 150 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

PNP TR2: Collector-emitter saturation voltage Fig. 5. as a function of collector current; typical values



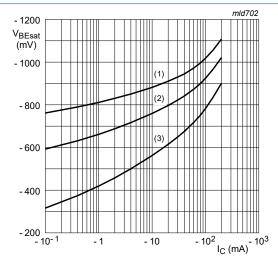
$$V_{CF} = -5 V$$

$$V_{CE} = -5 V$$

(1) $T_{amb} = -55 \, ^{\circ}C$

$$(3) T_{amb} = 150 °C$$

PNP TR2: Base-emitter voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 6. PNP TR2: Base-emitter saturation voltage as a function of collector current; typical values

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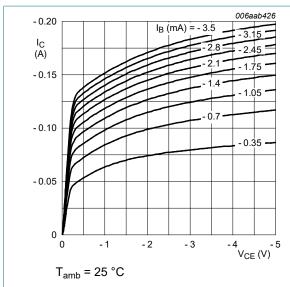


Fig. 7. PNP transistor: Collector current as a function of collector-emitter voltage; typical values

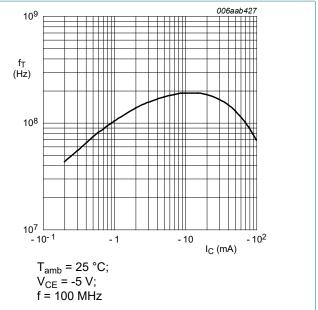


Fig. 8. PNP transistor: Transition frequency as a function of collector current; typical values

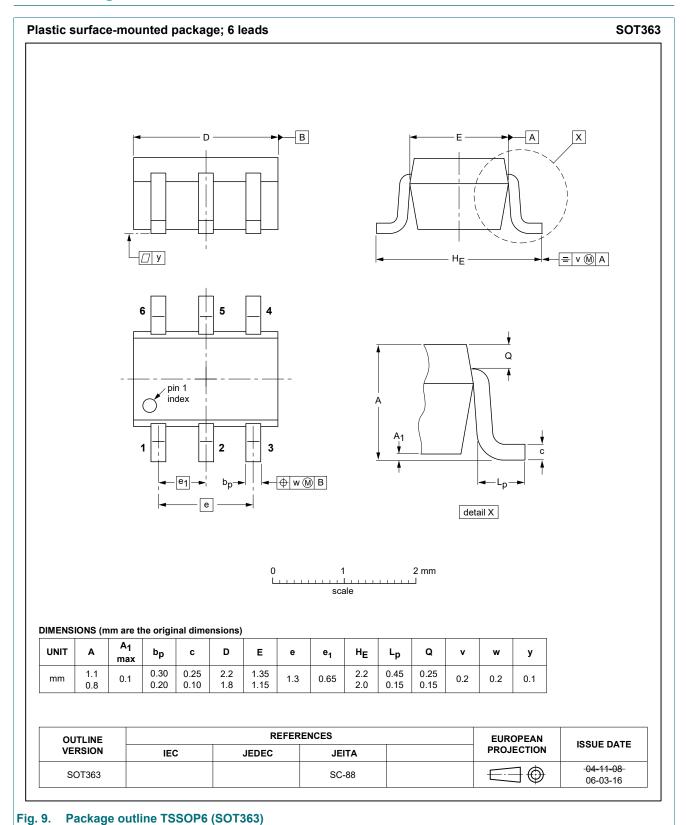
11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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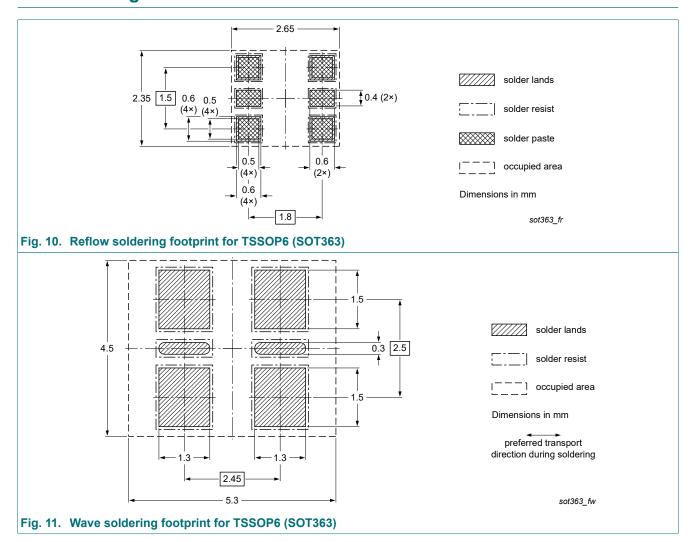
12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BC857BS-Q	20210629	Product data sheet	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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